

# Low Voltage Operation Omnipolar Detection Type Hall Effect Switch IC

## **General Description**

The ET3713B30 is a high sensitivity and high-accuracy Omnipolar Hall effect switch IC that operates at a low voltage and low current consumption. ET3713B30 has two CMOS output terminal for N and S pole. The output voltage will be pulled low when this IC detects the magnetic flux density is larger than operate point( $B_{OPN}/B_{OPS}$ ) and the output voltage will recover to high until the magnetic flux density is smaller than the release point( $B_{RPN}/B_{RPS}$ ). Using this IC with a magnet makes it possible to detect the open / close status in various applications.

To achieve a high-density mounting the ET3713B30 uses a super-small DFN4 package.

The ET3713B30 is suitable for battery powered portable devices such as mobile phones and portable PCs etc. due to its low voltage operation and low current consumption, the average current consumption is only typ. 2.5µA with a 1.8V supply.

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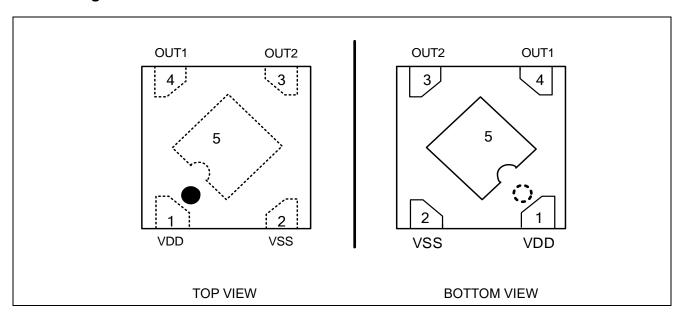
#### **Features**

- Pole detection: Omnipolar pole
- Output logic: Dual active low output for N/S-pole
- Output form: CMOS output, no external pull-up resistor required
- Operating point: Bop = 3.0 mT typ.
- Operating cycle: tcycle = 50 ms typ.
- Current consumption: I<sub>DD</sub> = 2.5 μA typ. at 1.8 V
- Power supply voltage range: V<sub>DD</sub> = 1.6 V to 5.5 V
- Operation temperature range: T<sub>A</sub> = -40 °C to +85 °C
- Lead-free (Sn 100%), halogen-free
- Super small DFN4(1×1) package

## Application

- Open/Close detection for flip mobile phones
- Smart cover for smart phones
- Smart cover for portable PCs, tablet PCs
- Digital video cameras and portable game consoles
- Home appliances

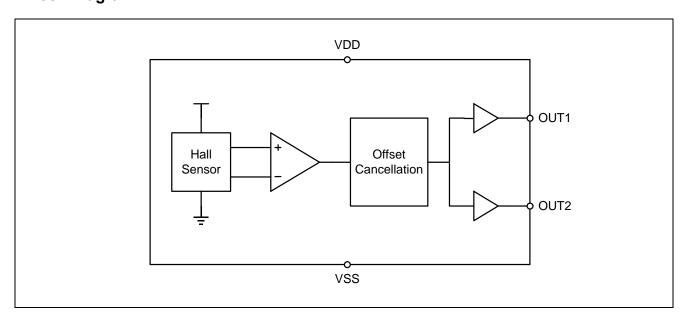
# Pin Configuration



# **Pin Function**

Pin No.	Pin Name	Pin Function
1	VDD	Power supply pin
2	VSS	Ground Pin
3	OUT2	S Pole Detection Output pin
4	OUT1	N Pole Detection Output pin
5	Thermal Pad	Leave floating

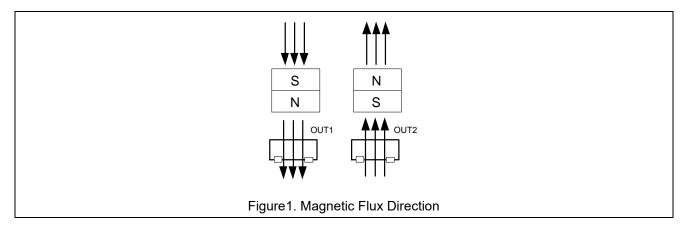
# **Block Diagram**



# **Functional Description**

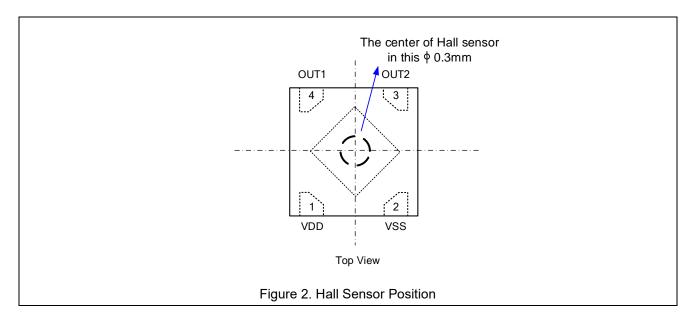
## Applied magnetic flux

The magnetic flux applied to ET3713B30 should on the vertical direction on marking surface. If not, the horizontal component has no effect to detection. ET3713B30 is omnipolar type detector, the corresponding output voltage is inverted when the sufficient S or N type magnetic flux is applied to IC.



#### **Hall sensor Position**

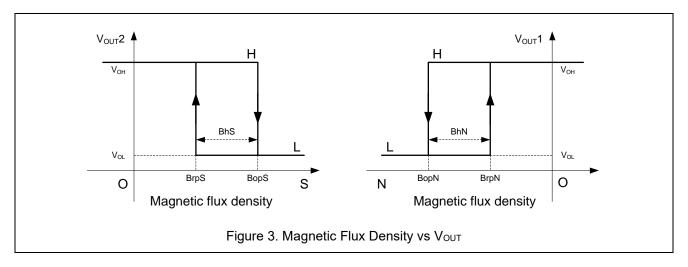
The Hall sensor embedded in ET3713B30 is at the center of IC. As show below, the position of this Hall sensor is located in the area indicated by a circle, the diameter size of which is about 0.3 mm.



#### **Detecting Operation**

ET3713B30 detects magnetic field periodically. When vertical component of the magnetic flux applied to IC exceeds the operating point ( $B_{OPN}$  or  $B_{OPS}$ ) such as the S or N pole of a magnet is moved closer to IC,  $V_{OUT}$  changes from "H" to "L". On the contrary, if magnetic flux is lower than the release point ( $B_{RPN}$  or  $B_{RPS}$ ),  $V_{OUT}$  changes from "L" to "H".

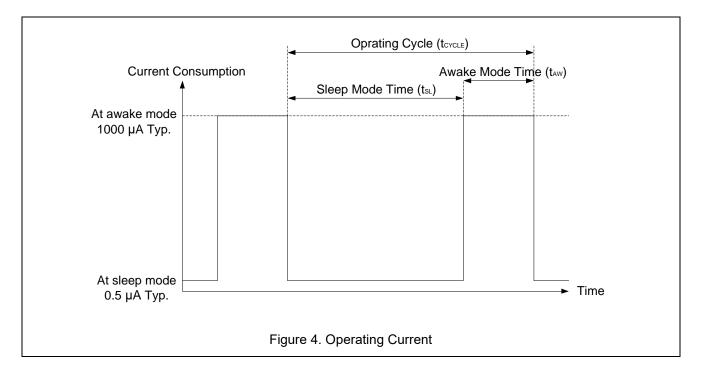
The relationship between the magnetic flux density and  $V_{\text{OUT}}$  is shown below.



#### **Operating Current**

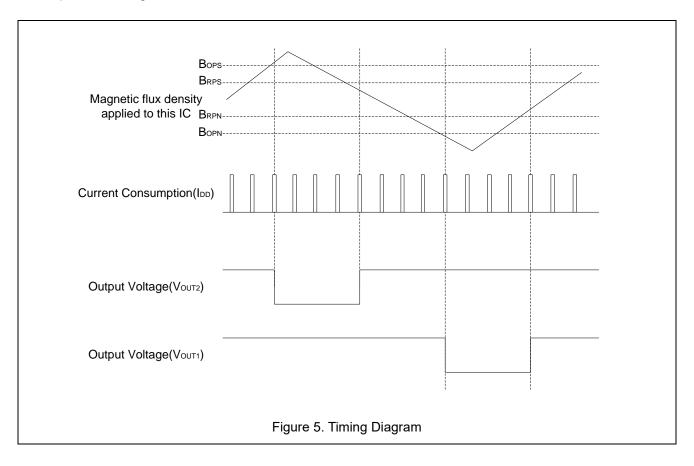
ET3713B30 performs the intermittent operation, therefore the average current consumption depends on the current in active mode , the active period ( $t_{AW}$ ), the current in sleep mode, and sleep period( $t_{SL}$ ). The active current is about 1000  $\mu$ A typically, and 0.5  $\mu$ A at sleep mode. Please refer to electrical characteristic table for detail.

The time dependency of the current consumption is shown below.



# **Timing Diagram**

The operation timing of this IC is shown below.



# **Absolute Maximum Ratings**

(T<sub>A</sub> = +25°C unless otherwise specified)

Symbol	Parameters	Rating	Unit
$V_{DD}$	Power supply voltage	Vss-0.3 ~ Vss+7.0	V
louт	Output current	±1.0	mA
Vout	Output voltage	Vss-0.3 ~ V <sub>DD</sub> +0.3	V
TA	Operation ambient temperature	-40 ~ +85	°C
T <sub>STG</sub>	Storage temperature	-40 ~ +125	°C
$\theta_{JA}$	Junction-to-ambient thermal resistance	250	°C/W

**Caution:** The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

#### **Electrical Characteristics**

 $(T_A = +25^{\circ}C, V_{DD} = 1.8 \text{ V}, \text{ unless otherwise specified})$ 

Symbol	Parameters	Conditions		Min	Тур	Max	Unit
$V_{DD}$	Power supply voltage	-		1.6	1.8	5.5	V
I <sub>DD</sub>	Current consumption	Average Supply Current			2.5	4.0	μA
Vol	Output voltage	CMOS output	$I_{OUT} = 0.5 \text{ mA}$			0.4	V
Vон	Output voltage	OUT1, OUT2	$I_{OUT} = -0.5 \text{ mA}$	V <sub>DD</sub> -0.4			V
t <sub>AW</sub>	Awake mode time				0.10		ms
tsL	Sleep mode time				50.0		ms
tcycle	Operating cycle	t <sub>AW</sub> + t <sub>SL</sub>			50.0	100.0	ms

# **Magnetic Characteristics**

 $(T_A = +25^{\circ}C, V_{DD} = 1.8 \text{ V}, \text{ unless otherwise specified})$ 

Parameters		Symbol	Conditions	Min	Тур	Max	Unit
0 11 141	S pole	Bops	T <sub>A</sub> = +25°C	1.6	3.0	4.0	mT <sup>(4)</sup>
			$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	1.4	3.0	4.6	
Operation point <sup>(1)</sup>	Ninolo	Г.	T <sub>A</sub> = +25°C	-4.0	-3.0	-1.6	<b>T</b>
	N pole	Вори	T <sub>A</sub> = -40°C to +85°C	-4.6	-3.0	-1.4	mT
Release point <sup>(2)</sup>	S pole B	В	T <sub>A</sub> = +25°C	1.1	2.2	3.5	mT
		B <sub>RPS</sub>	T <sub>A</sub> = -40°C to +85°C	0.9	2.2	3.9	
	N pole B <sub>RPN</sub>	1	T <sub>A</sub> = +25°C	-3.5	-2.2	-1.1	T
		T <sub>A</sub> = -40°C to +85°C	-3.9	-2.2	-0.9	mT	
Hysteresis width <sup>(3)</sup>	S pole B <sub>HS</sub>	D	B <sub>HS</sub> = B <sub>OPS</sub> - B <sub>RPS</sub>	0.0	0.0		Т
		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	0.3	8.0		mT	
	N polo	D	B <sub>HN</sub> =   B <sub>OPN</sub> - B <sub>RPN</sub>	0.3	0.0		Т
	N pole B <sub>HN</sub>	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	0.3	8.0		mT	

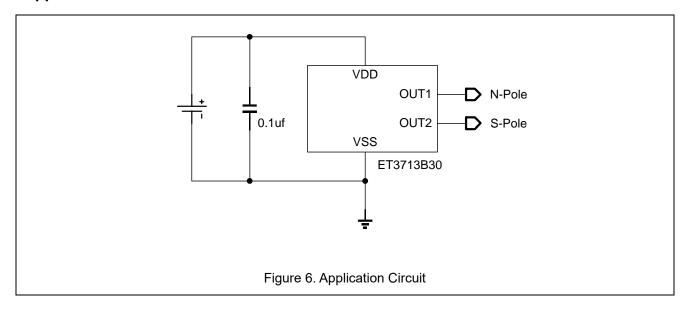
## Notes:

- (1) Operating points ( $B_{OPN}$ ,  $B_{OPS}$ ):  $B_{OPN}$  and  $B_{OPS}$  are the values of magnetic flux density triggers the output voltage ( $V_{OUT}$ ) to low by increasing the N pole or S pole magnetic flux density applied to this IC. Even when the magnetic flux density is larger than  $B_{OPN}$  or  $B_{OPS}$ ,  $V_{OUT}$  status is held.
- (2) Release points ( $B_{RPN}$ ,  $B_{RPS}$ ):  $B_{RPN}$  and  $B_{RPS}$  are the values of magnetic flux density makes the output voltage ( $V_{OUT}$ ) recover to high by decreasing the N pole or S pole magnetic flux density applied to this IC. Even when the magnetic flux density is lower than  $B_{RPN}$  or  $B_{RPS}$ ,  $V_{OUT}$  status is held.
- (3) Hysteresis widths (B<sub>HN</sub>, B<sub>HS</sub>): B<sub>HN</sub> and B<sub>HS</sub> are the difference between B<sub>OPN</sub> and B<sub>RPN</sub>, and B<sub>OPS</sub> and B<sub>RPS</sub>, respectively.

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(4) The unit of magnetic density mT can be converted by using the formula 1 mT = 10 Gauss.

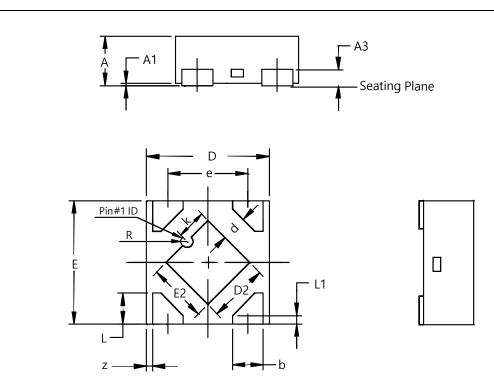
# **Application Circuit**



#### **Precautions**

- The power supply for this IC should has low impedance, the IC may malfunction due to a supply voltage drop caused by feed through current.
- Power supply voltage rapidly changing may cause IC malfunction.
- Large stress on this IC may affect the magnetic characteristics. Avoid large stress applied to the IC on a board.

# **Package Dimension**

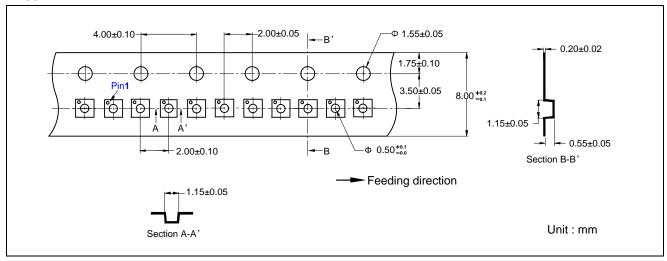


COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX			
Α	>0.3	0.38	0.40			
<b>A</b> 1	0.00	0.03	0.05			
А3	0.127REF					
b	0.20	0.25	0.30			
D	0.95	1.00	1.05			
D2	0.43	0.48	0.53			
E	0.95	1.00	1.05			
E2	0.43	0.48	0.53			
d	-	0.205	-			
е	0.65BSC					
k	0.19	0.24	0.29			
L	0.15	0.25	0.35			
L1	0.02	0.07	0.12			
R	0.02	0.05	0.08			
Z	-	0.050	-			

# ET3713B30

#### Reel



## **Pocket**

Package	Qty	Carrier	
DFN4(1×1)	10000	7" Tape and Reel	

# Revision History and Checking Table

Version	Date	Revision Item	Modifier	Function & Spec	Package & Tape
				Checking	Checking
0.0	2019.11.20	Preliminary Version	Shibo	Wanggp	Zhujl
0.1	2023.8.20	Update package	Shibo	Chenh	Chenh
0.00 0.00		Magnetic Characteristics	Chiha	Chanh	Chark
0.2	2023.9.25	Add temperature range	Shibo	Chenh	Chenh
1.0	2023.10.20	Released Version	Tianqihe	Chenh	Chenh